

IXTH12N120 Information


For Reference Only

Part Number [IXTH12N120](#)
Manufacturer IXYS
Category Discrete Semiconductor Products
[Transistors - FETs, MOSFETs - Single](#)
Description MOSFET N-CH 1200V 12A TO-247
Package TO-247-3
 For the pricing/inventory/lead time, please contact us
 Website: <https://www.heisener.com>
 E-mail: salesdept@heisener.com


[Request a Quote](#)
Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.


IXTH12N120 Specifications

Manufacturer Part Number	IXTH12N120
Manufacturer	IXYS
Category	Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single
Package	TO-247-3
Series	-
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	1200V
Current - Continuous Drain (Id) @ 25°C	12A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	95nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	3400pF @ 25V
Vgs (Max)	±30V
FET Feature	-
Power Dissipation (Max)	500W (Tc)
Rds On (Max) @ Id, Vgs	1.4 Ohm @ 6A, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	TO-247 (IXTH)
Package / Case	TO-247-3

[Report errors?](#)

IXTH12N120 Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

IXTH12N120 Payment Methods



IXTH12N120 Shipping Methods



If you have any question about IXTH12N120, please do not hesitate to contact us!

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